

## Description

The AP2145 is integrated high-side power switches optimized for Universal Serial Bus (USB) and other hot-swap applications. The family of devices complies with USB 2.0 and available with active low Enable input. They offer current and thermal limiting and short circuit protection as well as controlled rise time and under-voltage lockout functionality. A 7ms deglitch capability on the open-drain Flag output prevents false over-current reporting and does not require any external components.

The AP2145 is available in SO-8 and MSOP-8EP packages.

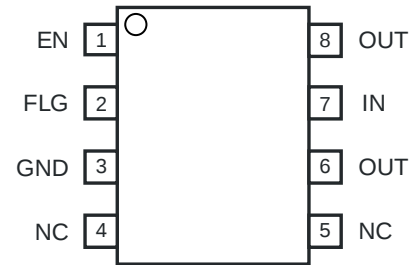
## Features

- Single USB Port Power Switches
- Over-Current and Thermal Protection
- 0.8A Accurate Current Limiting
- Reverse Current Blocking
- 90mΩ On-Resistance
- Input Voltage Range: 2.7V to 5.5V
- 0.6ms Typical Rise Time
- Very Low Shutdown Current: 1μA (Max)
- Fault Report (FLG) with Blanking Time (7ms Typ)
- ESD Protection: 6kV HBM, 400V MM
- Active Low (AP2145) Enable
- Ambient Temperature Range -40°C to +85°C
- SO-8 and MSOP-8EP (Exposed Pad): Available in "Green" Molding Compound (No Br, Sb)
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- UL Recognized, File Number E322375
- IEC60950-1 CB Scheme Certified

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

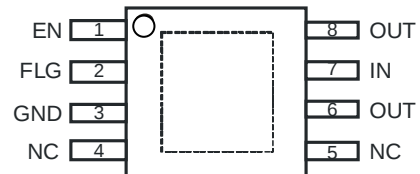
## Pin Assignments

(Top View)



SO-8

(Top View)

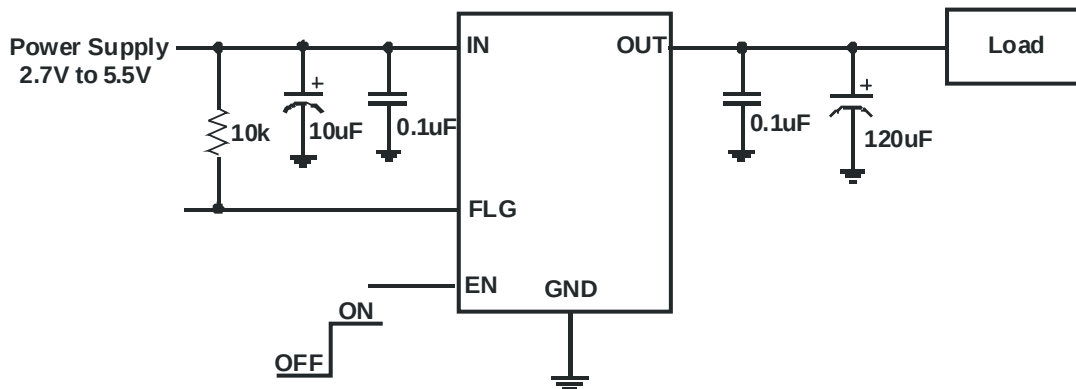


MSOP-8EP

## Applications

- Consumer Electronics – LCD TV & Monitor, Game Machines
- Communications – Set-Top-Box, GPS, Smartphone
- Computing – Laptop, Desktop, Servers, Printers, Docking Station, HUB

## Typical Applications Circuit



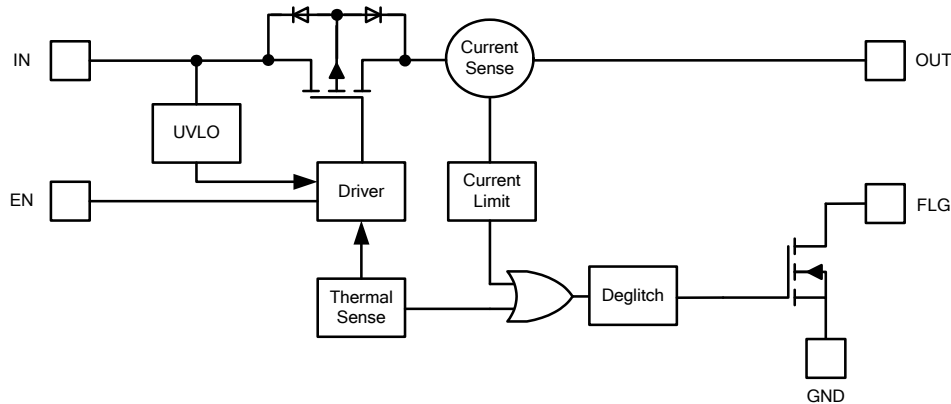
## Available Options

| Part Number | Channel | Enable Pin (EN) | Current Limit (Typ) | Recommended Maximum Continuous Load Current |
|-------------|---------|-----------------|---------------------|---------------------------------------------|
| AP2145      | 1       | Active Low      | 0.8A                | 0.5A                                        |

## Pin Descriptions

| Pin Name    | Pin Number |             | Function                                                                                                                                                                              |
|-------------|------------|-------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|             | SO-8       | MSOP-8EP    |                                                                                                                                                                                       |
| EN          | 1          | 1           | Enable input, active low (AP2145)                                                                                                                                                     |
| FLG         | 2          | 2           | Over-current and over-temperature fault report; open-drain flag is active low when triggered.                                                                                         |
| GND         | 3          | 3           | Ground                                                                                                                                                                                |
| NC          | 4, 5       | 4, 5        | No internal connection                                                                                                                                                                |
| OUT         | 6, 8       | 6, 8        | Voltage output pin (all OUT pins must be tied together externally)                                                                                                                    |
| IN          | 7          | 7           | Voltage input pin                                                                                                                                                                     |
| Exposed Pad | —          | Exposed Pad | Exposed Pad:<br>It should be externally connected to GND plane and thermal mass for enhanced thermal impedance.<br><b>It should not be used as electrical ground conduction path.</b> |

## Functional Block Diagram



## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Symbol                             | Parameter                          | Ratings              | Unit |
|------------------------------------|------------------------------------|----------------------|------|
| ESD HBM                            | Human Body Model ESD Protection    | 6                    | kV   |
| ESD MM                             | Machine Model ESD Protection       | 400                  | V    |
| V <sub>IN</sub>                    | Input Voltage                      | 6.5                  | V    |
| V <sub>OUT</sub>                   | Output Voltage                     | V <sub>IN</sub> +0.3 | V    |
| V <sub>EN</sub> , V <sub>FLG</sub> | Enable Voltage                     | 6.5                  | V    |
| I <sub>LOAD</sub>                  | Maximum Continuous Load Current    | Internal Limited     | A    |
| T <sub>J(MAX)</sub>                | Maximum Junction Temperature       | +150                 | °C   |
| T <sub>ST</sub>                    | Storage Temperature Range (Note 4) | -65 to +150          | °C   |

**Caution:** Stresses greater than the 'Absolute Maximum Ratings' specified above, may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.  
Semiconductor devices are ESD sensitive and may be damaged by exposure to ESD events. Suitable ESD precautions should be taken when handling and transporting these devices.

**Note:** 4. UL Recognized Rating from -30°C to +70°C (Diodes Incorporated qualified T<sub>ST</sub> from -65°C to +150°C).

## Recommended Operating Conditions (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Symbol           | Parameter                     | Min | Max             | Unit |
|------------------|-------------------------------|-----|-----------------|------|
| V <sub>IN</sub>  | Input Voltage                 | 2.7 | 5.5             | V    |
| I <sub>OUT</sub> | Output Current                | 0   | 500             | mA   |
| V <sub>IL</sub>  | EN Input Logic Low Voltage    | 0   | 0.8             | V    |
| V <sub>IH</sub>  | EN Input Logic High Voltage   | 2.0 | V <sub>IN</sub> | V    |
| T <sub>A</sub>   | Operating Ambient Temperature | -40 | +85             | °C   |

## Electrical Characteristics (@T<sub>A</sub> = +25°C, V<sub>IN</sub> = +5.0V, unless otherwise specified.)

| Symbol              | Parameter                              | Test Conditions                                                                                                               | Min | Typ. | Max | Unit |
|---------------------|----------------------------------------|-------------------------------------------------------------------------------------------------------------------------------|-----|------|-----|------|
| V <sub>UVLO</sub>   | Input UVLO                             | R <sub>LOAD</sub> = 1kΩ                                                                                                       | 1.6 | 1.9  | 2.5 | V    |
| I <sub>SHDN</sub>   | Input Shutdown Current                 | Disabled, OUT = open                                                                                                          | —   | 0.5  | 1   | μA   |
| I <sub>Q</sub>      | Input Quiescent Current                | Enabled, OUT = open                                                                                                           | —   | 45   | 70  | μA   |
| I <sub>LEAK</sub>   | Input Leakage Current                  | Disabled, OUT grounded                                                                                                        | -1  | —    | 1   | μA   |
| I <sub>REV</sub>    | Reverse Leakage Current                | Disabled, V <sub>IN</sub> = 0V, V <sub>OUT</sub> = 5V, I <sub>REV</sub> at V <sub>IN</sub>                                    | —   | 1    | —   | μA   |
| R <sub>DS(ON)</sub> | Switch On-Resistance                   | V <sub>IN</sub> = 5V, I <sub>OUT</sub> = 0.5A, -40°C ≤ T <sub>A</sub> ≤ +85°C                                                 | —   | 90   | 140 | mΩ   |
|                     |                                        | MSOP-8EP                                                                                                                      | —   | 95   | 140 | mΩ   |
|                     |                                        | SO-8                                                                                                                          | —   | 120  | 160 | mΩ   |
| I <sub>SHORT</sub>  | Short-Circuit Current Limit            | Enabled into short circuit, C <sub>IN</sub> = 10μF, C <sub>L</sub> = 100μF                                                    | —   | 0.7  | —   | A    |
| I <sub>LIMIT</sub>  | Over-Load Current Limit                | V <sub>IN</sub> = 5V, V <sub>OUT</sub> = 4.5V, C <sub>IN</sub> = 10μF, C <sub>L</sub> = 100μF, -40°C ≤ T <sub>A</sub> ≤ +85°C | 0.6 | 0.8  | 1.0 | A    |
| I <sub>TRIG</sub>   | Current Limiting Trigger Threshold     | Output Current Slew rate (<100A/s), C <sub>IN</sub> = 10μF, C <sub>L</sub> = 22μF                                             | —   | 1.0  | —   | A    |
| t <sub>SHORT</sub>  | Short-Circuit Response Time            | V <sub>OUT</sub> = 0V to I <sub>OUT</sub> = I <sub>LIMIT</sub> (short applied to output), C <sub>L</sub> = 100μF              | —   | 10   | —   | μs   |
| V <sub>IL</sub>     | EN Input Logic Low Voltage             | V <sub>IN</sub> = 2.7V to 5.5V                                                                                                | —   | —    | 0.8 | V    |
| V <sub>IH</sub>     | EN Input Logic High Voltage            | V <sub>IN</sub> = 2.7V to 5.5V                                                                                                | 2   | —    | —   | V    |
| I <sub>SINK</sub>   | EN Input Leakage                       | V <sub>EN</sub> = 5V                                                                                                          | —   | —    | 1   | μA   |
| I <sub>O-LEAK</sub> | Output Leakage Current                 | Disabled                                                                                                                      | —   | —    | 1   | μA   |
| t <sub>D(ON)</sub>  | Output Turn-On Delay Time              | C <sub>L</sub> = 1μF, R <sub>LOAD</sub> = 10Ω                                                                                 | —   | 0.05 | —   | ms   |
| t <sub>r</sub>      | Output Turn-On Rise Time               | C <sub>L</sub> = 1μF, R <sub>LOAD</sub> = 10Ω                                                                                 | —   | 0.6  | 1.5 | ms   |
| t <sub>D(OFF)</sub> | Output Turn-Off Delay Time             | C <sub>L</sub> = 1μF, R <sub>LOAD</sub> = 10Ω                                                                                 | —   | 0.01 | —   | ms   |
| t <sub>f</sub>      | Output Turn-Off Fall Time              | C <sub>L</sub> = 1μF, R <sub>LOAD</sub> = 10Ω                                                                                 | —   | 0.05 | 0.1 | ms   |
| R <sub>FLG</sub>    | FLG Output FET On-Resistance           | V <sub>IN</sub> = 3.3V or 5V, C <sub>IN</sub> = 10μF, I <sub>FLG</sub> = 10mA                                                 | —   | 20   | 40  | Ω    |
| I <sub>FLG</sub>    | FLG Leakage Current                    | V <sub>FLG</sub> = 5V                                                                                                         | —   | 1    | —   | μA   |
| t <sub>BILANK</sub> | FLG Blanking Time                      | V <sub>IN</sub> = 3.3V or 5V, C <sub>IN</sub> = 10μF, C <sub>L</sub> = 100μF                                                  | 4   | 7    | 15  | ms   |
| T <sub>SHDN</sub>   | Thermal Shutdown Threshold             | Enabled, R <sub>LOAD</sub> = 1kΩ                                                                                              | —   | +135 | —   | °C   |
| T <sub>HYS</sub>    | Thermal Shutdown Hysteresis            | —                                                                                                                             | —   | +25  | —   | °C   |
| θ <sub>JA</sub>     | Thermal Resistance Junction-to-Ambient | SO-8 (Note 5)                                                                                                                 | —   | 110  | —   | °C/W |
|                     |                                        | MSOP-8EP (Note 6)                                                                                                             | —   | 60   | —   | °C/W |

Notes: 5. Test condition for SO-8: Device mounted on FR-4, 2oz copper, with minimum recommended pad layout.  
6. Test condition for MSOP-8EP: Device mounted on 2" x 2" FR-4 substrate PC board, 2oz copper, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane.

## Typical Performance Characteristics

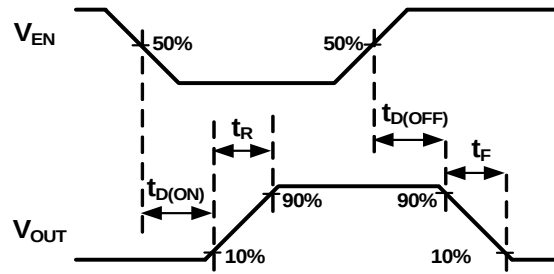
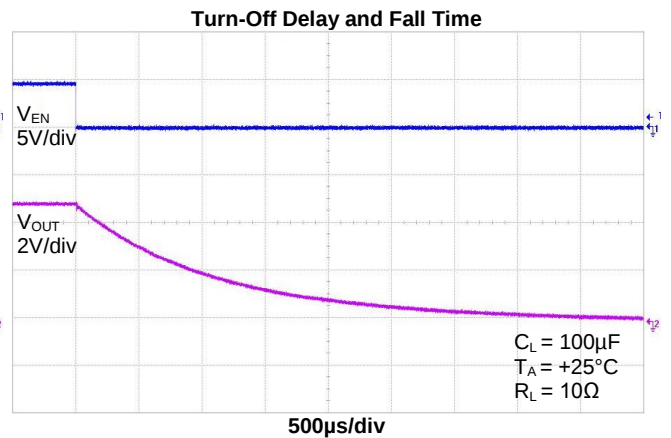
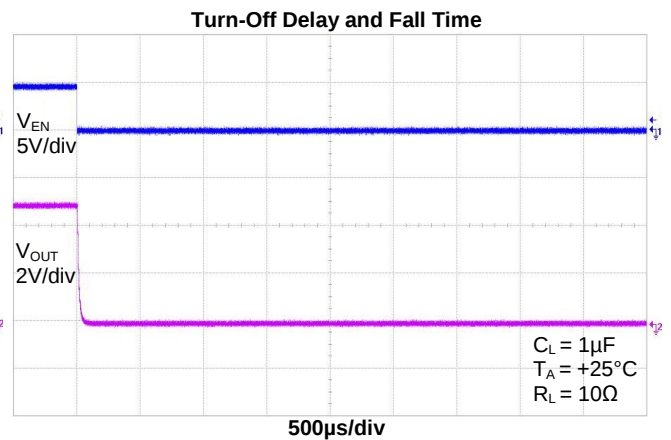
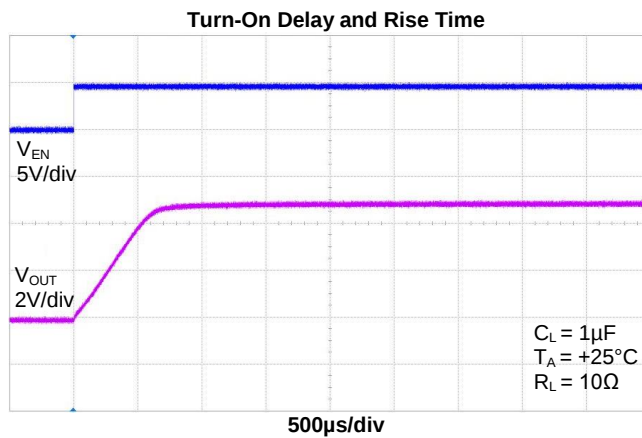


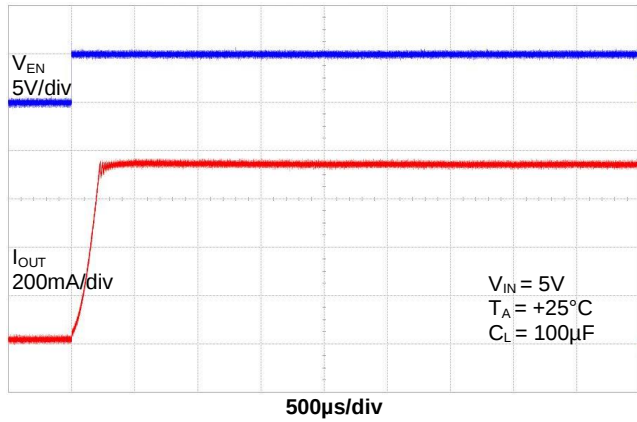
Figure 1. Voltage Waveforms

All Enable Plots are for AP2155 (EOL) Active High

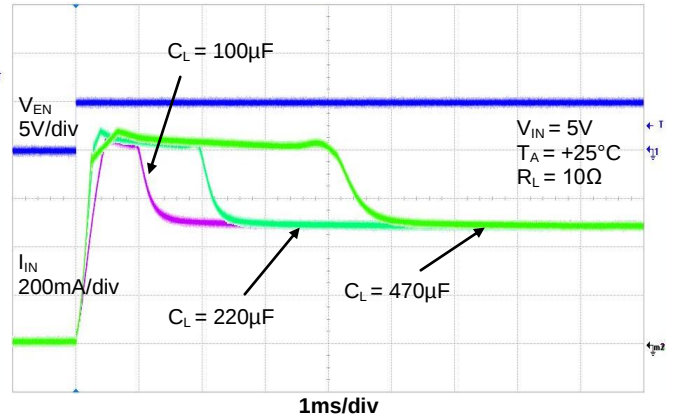


## Typical Performance Characteristics (Cont.)

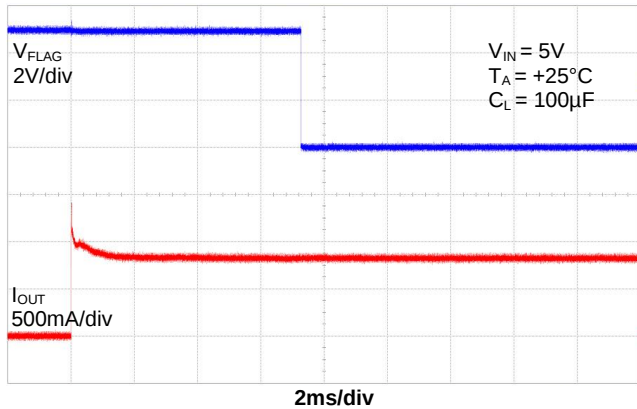
Short Circuit Current,  
Device Enabled Into Short



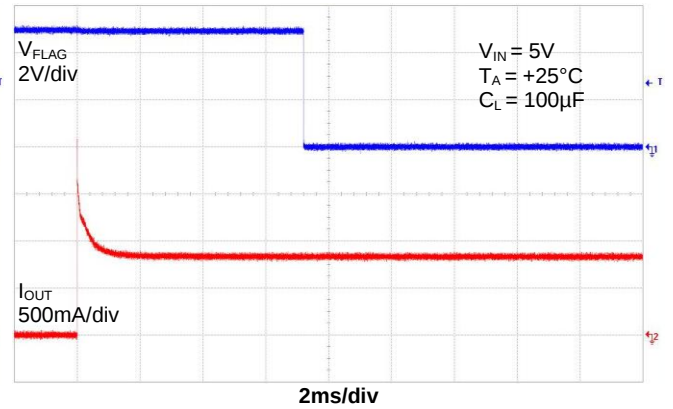
Inrush Current



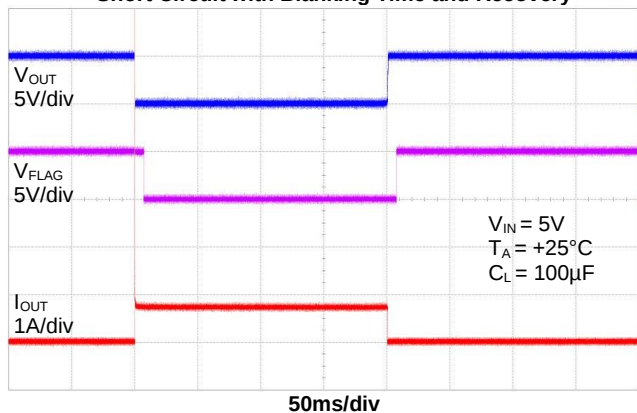
3  $\Omega$  Load Connected to Enabled Device



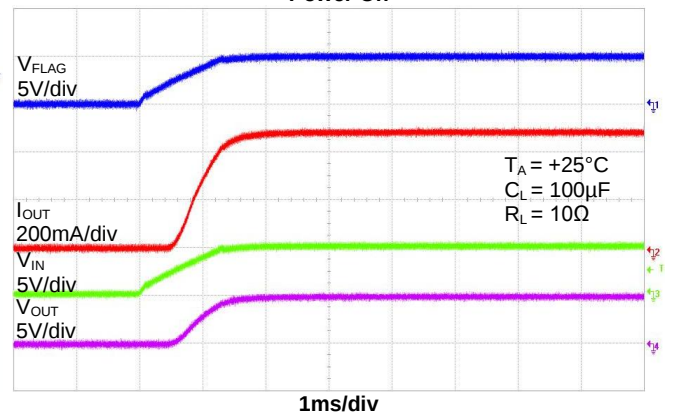
2  $\Omega$  Load Connected to Enabled Device



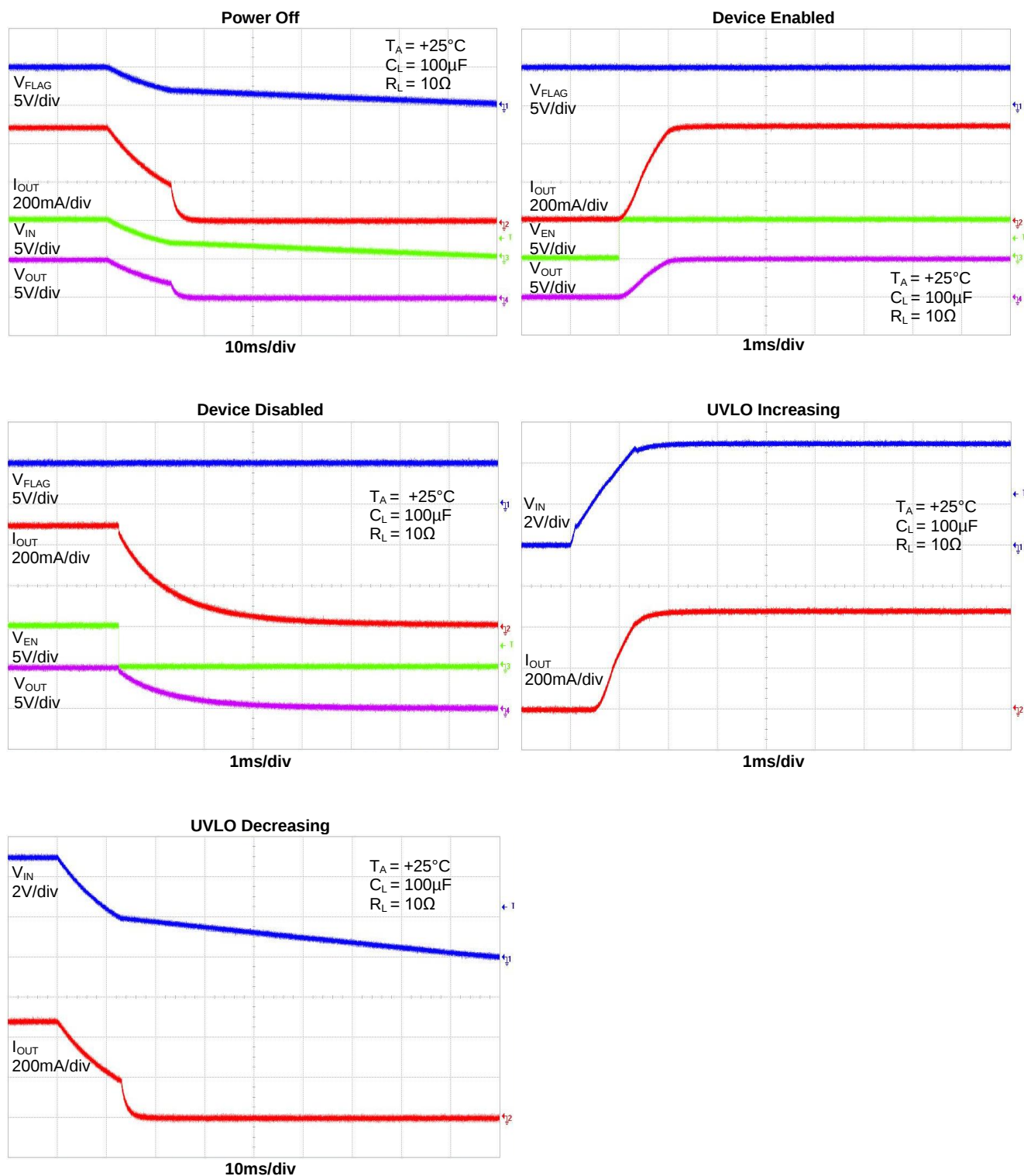
Short Circuit with Blanking Time and Recovery



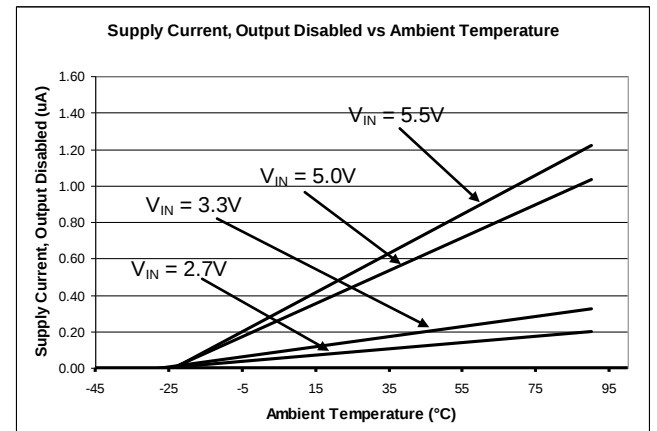
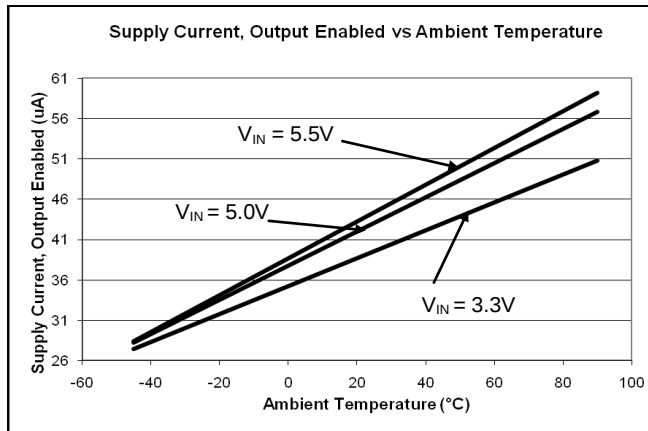
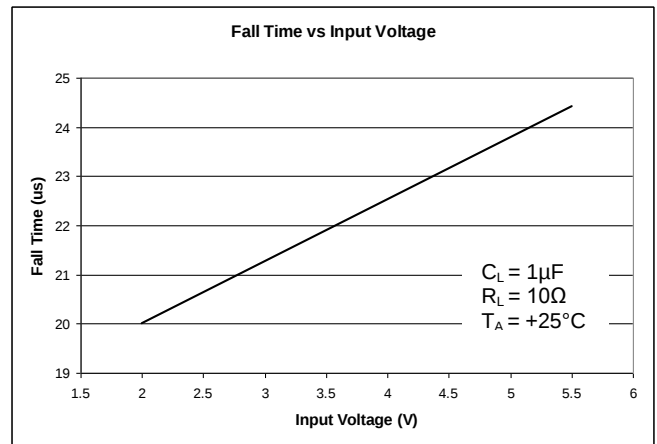
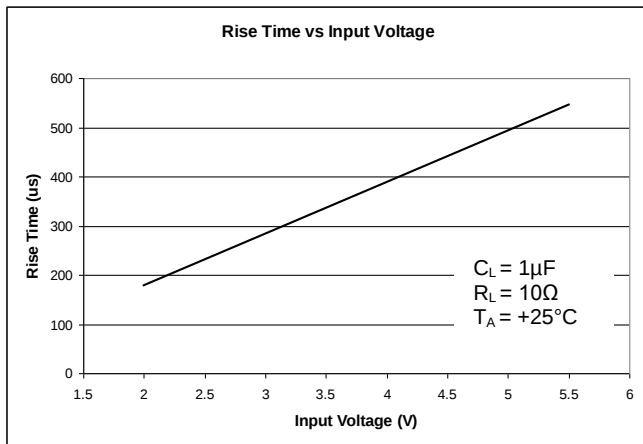
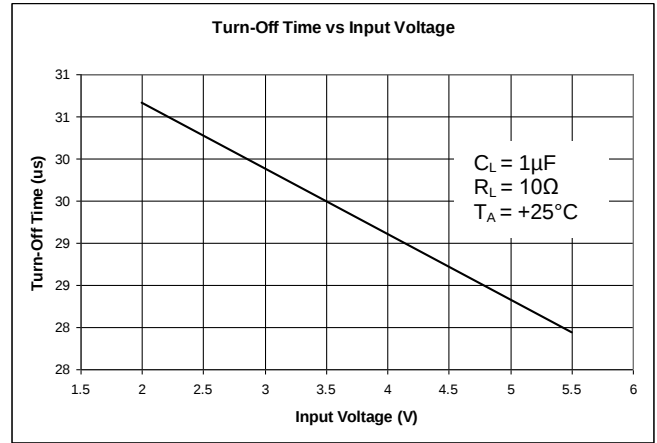
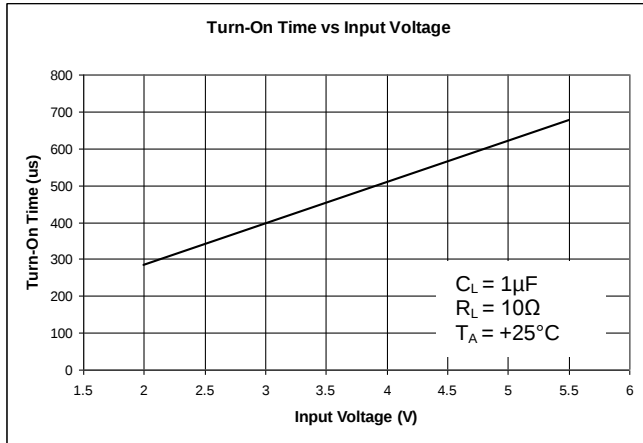
Power On



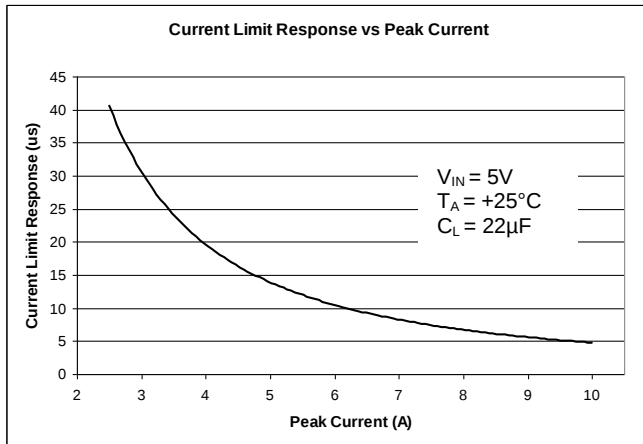
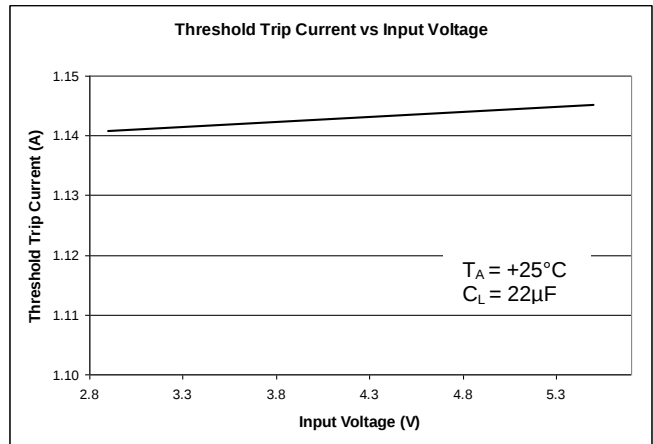
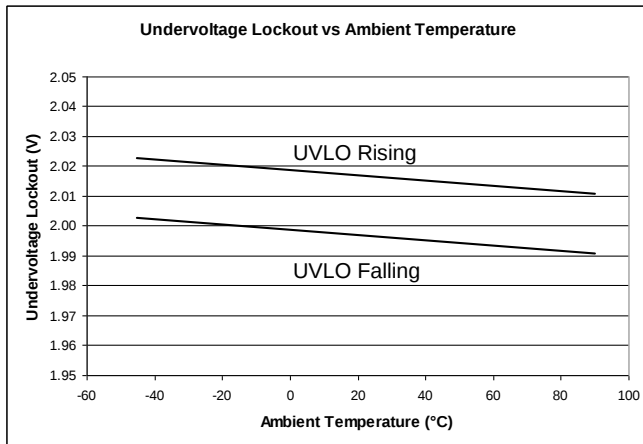
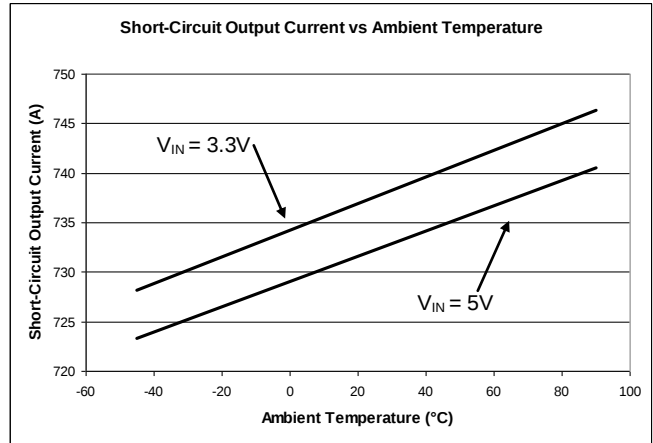
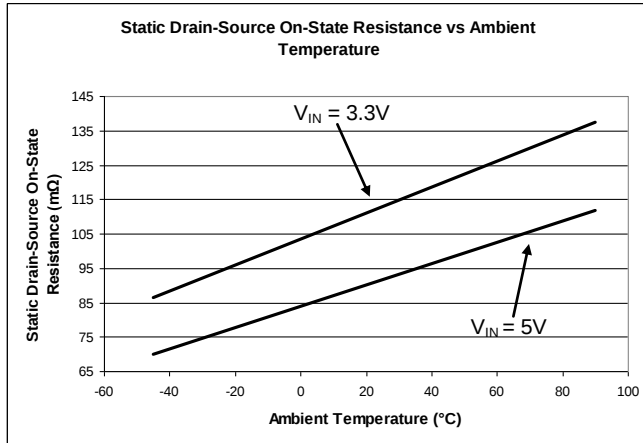
# Typical Performance Characteristics (Cont.)



## Typical Performance Characteristics (Cont.)



## Typical Performance Characteristics (Cont.)



## Application Information

### Power Supply Considerations

A 0.1μF to 1μF X7R or X5R ceramic bypass capacitor between IN and GND, close to the device, is recommended. Placing a high-value electrolytic capacitor on the input and output pin(s) is recommended when the output load is heavy. This precaution reduces power-supply transients that may cause ringing on the input. Additionally, bypassing the output with a 0.01μF to 0.1μF ceramic capacitor improves the immunity of the device to short-circuit transients.

### Over-Current and Short Circuit Protection

An internal sensing FET is employed to check for over-current conditions. Unlike current-sense resistors, sense FETs do not increase the series resistance of the current path. When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Complete shutdown occurs only if the fault stays long enough to activate thermal limiting.

Three possible overload conditions can occur. In the first condition, the output has been shorted to GND before the device is enabled or before  $V_{IN}$  has been applied. The AP2145 senses the short circuit and immediately clamps output current to a certain safe level namely  $I_{LIMIT}$ .

In the second condition, an output short or an overload occurs while the device is enabled. At the instance the overload occurs, higher current may flow for a very short period of time before the current limit function can react. After the current limit function has tripped (reached the over-current trip threshold), the device switches into current limiting mode and the current is clamped at  $I_{LIMIT}$ .

In the third condition, the load has been gradually increased beyond the recommended operating current. The current is permitted to rise until the current-limit threshold ( $I_{TRIG}$ ) is reached or until the thermal limit of the device is exceeded. The AP2145 is capable of delivering current up to the current-limit threshold without damaging the device. Once the threshold has been reached, the device switches into its current limiting mode and is set at  $I_{LIMIT}$ .

To protect against short circuit to GND at extremely low temperature ( $< -30^{\circ}\text{C}$ ), a minimum 120μF electrolytic capacitor on the output pin is recommended. A correct capacitor type with capacitor voltage rating and temperature characteristics must be properly chosen so that capacitance value does not drop too low at the extremely low temperature operation. A recommended capacitor should have temperature characteristics of less than 10% variation of capacitance change when operated at extremely low temp. Our recommended aluminum electrolytic capacitor type is Panasonic FC series.

### FLG Response

When an over-current or over-temperature shutdown condition is encountered, the FLG open-drain output goes active low after a nominal 7ms deglitch timeout. The FLG output remains low until both over-current and over-temperature conditions are removed. Connecting a heavy capacitive load to the output of the device can cause a momentary over-current condition, which does not trigger the FLG due to the 7ms deglitch timeout. The AP2145 is designed to eliminate false over-current reporting without the need of external components to remove unwanted pulses.

### Power Dissipation and Junction Temperature

The low on-resistance of the internal MOSFET allows the small surface-mount packages to pass large current. Using the maximum operating ambient temperature ( $T_A$ ) and  $R_{DS(ON)}$ , the power dissipation can be calculated by:

$$P_D = R_{DS(ON)} \times I^2$$

Finally, calculate the junction temperature:

$$T_J = P_D \times R_{\theta JA} + T_A$$

Where:

$T_A$  = Ambient temperature  $^{\circ}\text{C}$

$R_{\theta JA}$  = Thermal resistance

$P_D$  = Total power dissipation

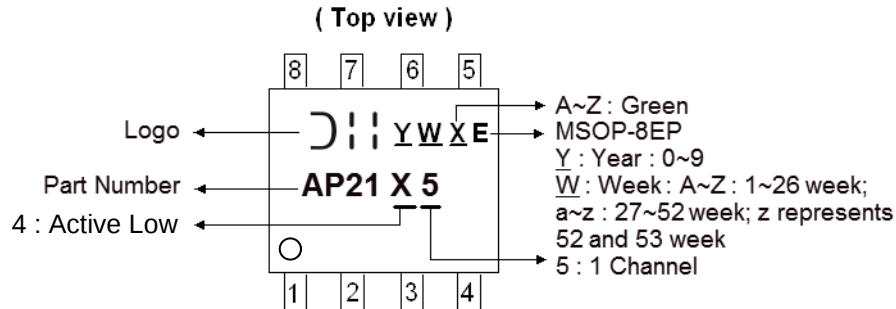
### Thermal Protection

Thermal protection prevents the IC from damage when heavy-overload or short-circuit faults are present for extended periods of time. The AP2145 implements a thermal sensing to monitor the operating junction temperature of the power distribution switch. Once the die temperature rises to approximately  $+140^{\circ}\text{C}$  due to excessive power dissipation in an over-current or short-circuit condition the internal thermal sense circuitry turns the power switch off, thus preventing the power switch from damage. Hysteresis is built into the thermal sense circuit allowing the device to cool down approximately  $+25^{\circ}\text{C}$  before the switch turns back on. The switch continues to cycle in this manner until the load fault or input power is removed. The FLG open-drain output is asserted when an over-temperature shutdown or over-current occurs with 7ms deglitch.



## Marking Information (Cont.)

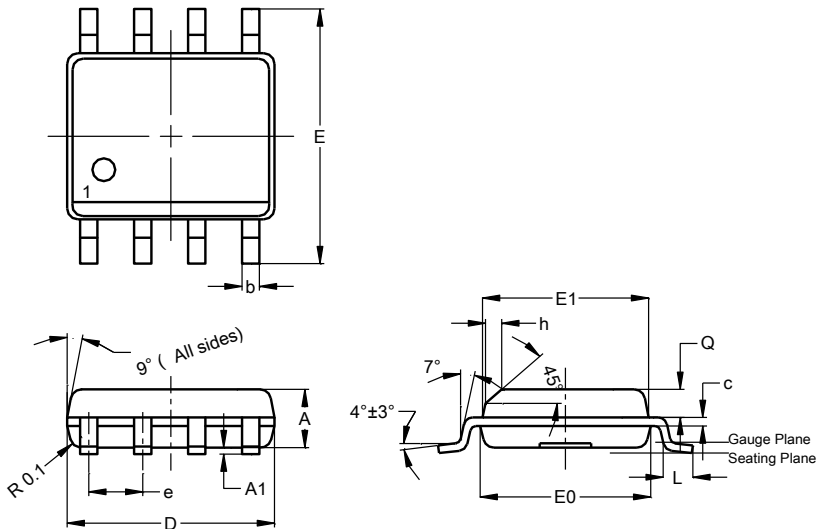
### (2) MSOP-8EP



## Package Outline Dimensions

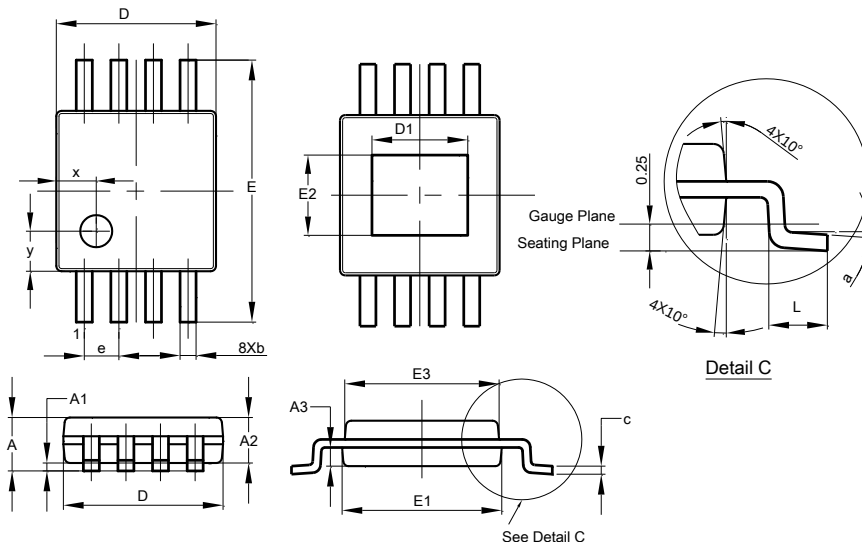
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### (1) Package Type: SO-8



| SO-8                 |      |      |      |
|----------------------|------|------|------|
| Dim                  | Min  | Max  | Typ  |
| A                    | 1.40 | 1.50 | 1.45 |
| A1                   | 0.10 | 0.20 | 0.15 |
| b                    | 0.30 | 0.50 | 0.40 |
| c                    | 0.15 | 0.25 | 0.20 |
| D                    | 4.85 | 4.95 | 4.90 |
| E                    | 5.90 | 6.10 | 6.00 |
| E1                   | 3.80 | 3.90 | 3.85 |
| E0                   | 3.85 | 3.95 | 3.90 |
| e                    | --   | --   | 1.27 |
| h                    | -    | --   | 0.35 |
| L                    | 0.62 | 0.82 | 0.72 |
| Q                    | 0.60 | 0.70 | 0.65 |
| All Dimensions in mm |      |      |      |

### (2) Package Type: MSOP-8EP

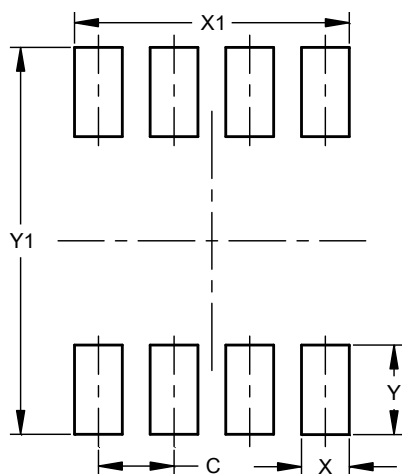


| MSOP-8EP             |      |      |       |
|----------------------|------|------|-------|
| Dim                  | Min  | Max  | Typ   |
| A                    | -    | 1.10 | -     |
| A1                   | 0.05 | 0.15 | 0.10  |
| A2                   | 0.75 | 0.95 | 0.86  |
| A3                   | 0.29 | 0.49 | 0.39  |
| b                    | 0.22 | 0.38 | 0.30  |
| c                    | 0.08 | 0.23 | 0.15  |
| D                    | 2.90 | 3.10 | 3.00  |
| D1                   | 1.60 | 2.00 | 1.80  |
| E                    | 4.70 | 5.10 | 4.90  |
| E1                   | 2.90 | 3.10 | 3.00  |
| E2                   | 1.30 | 1.70 | 1.50  |
| E3                   | 2.85 | 3.05 | 2.95  |
| e                    | -    | -    | 0.65  |
| L                    | 0.40 | 0.80 | 0.60  |
| a                    | 0°   | 8°   | 4°    |
| x                    | -    | -    | 0.750 |
| y                    | -    | -    | 0.750 |
| All Dimensions in mm |      |      |       |

## Suggested Pad Layout

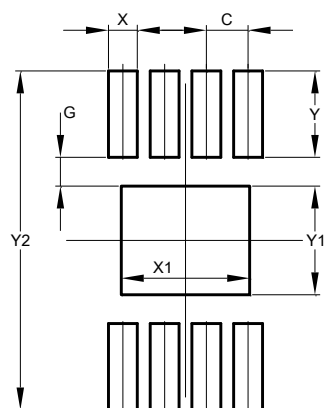
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### (1) Package Type: SO-8



| Dimensions | Value (in mm) |
|------------|---------------|
| C          | 1.27          |
| X          | 0.802         |
| X1         | 4.612         |
| Y          | 1.505         |
| Y1         | 6.50          |

### (2) Package Type: MSOP-8EP



| Dimensions | Value (in mm) |
|------------|---------------|
| C          | 0.650         |
| G          | 0.450         |
| X          | 0.450         |
| X1         | 2.000         |
| Y          | 1.350         |
| Y1         | 1.700         |
| Y2         | 5.300         |

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**Стандарт  
Электрон  
Связь**

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